

FORM 1449* INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION (Use several sheets if necessary)	Docket Number: 10873.1391US01	Application Number: 10/757,864
	Applicant: KITAOKA et al.	
	Filing Date: January 15, 2004	Group Art Unit: 1722

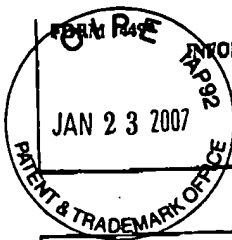
U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
MS	5,868,837	February, 1999	DiSalvo et al.			
	6,121,121	September, 2000	Koide			
	6,270,569	August, 2001	Shibata, et al.			
	6,503,610	January, 2003	Hiramatsu, et al.			
	2003/0042496	March, 2003	Sasaoka			
	6,592,663	July, 2003	Sarayama, et al.			
	6,614,059	September, 2003	Tsujimura, et al.			
	6,667,252	December, 2003	Miyajima, et al.			
	2004/0124434	July, 2004	D'Evelyn et al.			
	2004/0147096	July, 2004	Kitaoka, et al.			
	2004/0183090	September, 2004	Kitaoka, et al.			
	2004/0262630	December, 2004	Kitaoka, et al.			
	2005/0011432	January, 2005	Kitaoka, et al.			
	2005/0082564	April, 2005	Kitaoka, et al.			
MS	2006/0051942	March, 2006	Sasaki, et al.			

FOREIGN PATENT DOCUMENTS							
	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO
MS	11-145516	May, 1999	Japan				
MS	2000-357663	December, 2000	Japan			Abstract	
MS	3409576	March, 2003	Japan			Abstract	
MS	2004/013385	February, 2004	WIPO				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)		
MS		Kawamura et al., "Growth of a Large GaN single Crystal Using the Liquid Phase Epitaxy (LPE) Technique" Japanese Journal of Applied Physics Vol. 42 (2003) pp. L4-L6
		M. Morishita, et al. "The growth mechanism of GaN singles crystals in Na flux system", Journal of the Japanese association for crystal growth, Vol. 30, No. 3 (2003), 801aA7
		M. Morishita, et al., "Growth of transparent GaN single crystals using LPE technique in Na flux system", The Japan Society of Applied Physics and Related Societies, Extended Abstracts (The 51st Spring Meeting, 2004), 29 p-YK-6

EXAMINER	/Matthew Song/	DATE CONSIDERED	02/15/2007	53148 PATENT TRADEMARK OFFICE
----------	----------------	-----------------	------------	---

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.



INFORMATION DISCLOSURE STATEMENT

IN AN APPLICATION

(Use several sheets if necessary)

Docket Number:

10873.1391U/801

Application Number:

10/757,864

Applicant: KITAOKA et al.

Filing Date: January 15, 2004

Group Art Unit: 1722

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
MS	5,868,837	February, 1999	DiSalvo et al.			
	6,121,121	September, 2000	Koide			
	6,270,569	August, 2001	Shibata, et al.			
	6,303,610	January, 2003	Hiramatsu, et al.			
	2003/0042496	March, 2003	Sasaka			
	6,592,663	July, 2003	Sarayama, et al.			
	6,614,059	September, 2003	Tsujimura, et al.			
	6,667,232	December, 2003	Miyajima, et al.			
	2004/0124434	July, 2004	D'Evelyn et al.			
	2004/0147096	July, 2004	Kitaoka, et al.			
	2004/0183090	September, 2004	Kitaoka, et al.			
	2004/0262630	December, 2004	Kitaoka, et al.			
	2005/0011432	January, 2005	Kitaoka, et al.			
	2005/0082364	April, 2005	Kitaoka, et al.			
MS	2006/0051942	March, 2006	Sasaki, et al.			

FOREIGN PATENT DOCUMENTS

	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO
MS	11-145516	May, 1999	Japan				
MS	2000-357663	December, 2000	Japan			Abstract	
MS	3409576	March, 2003	Japan			Abstract	
MS	2004/013385	February, 2004	WIPO				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

MS		Kawamura et al., "Growth of a Large GaN single Crystal Using the Liquid Phase Epitaxy (LPE) Technique" Japanese Journal of Applied Physics Vol. 42 (2003) pp. L4-L6				
		M. Morishita, et al. "The growth mechanism of GaN single crystals in Na flux system", Journal of the Japanese association for crystal growth, Vol. 30, No. 3 (2003), 801A7				
		M. Morishita, et al., "Growth of transparent GaN single crystals using LPE technique in Na flux system", The Japan Society of Applied Physics and Related Societies, Extended Abstracts (The 51st Spring Meeting, 2004), 29 p-YK-6				

53148

PATENT TRADEMARK OFFICE

EXAMINER

/Matthew Song/

DATE CONSIDERED

02/15/2007

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.

BEST AVAILABLE COPY